

# **DSA 20 C 100 PN**

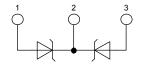
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## **Schottky Diode**

High Performance Schottky Diode Low Loss and Soft Recovery Common Cathode

Part number

**DSA 20 C 100 PN** 

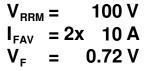


#### Features / Advantages:

- Very low Vf
- Extremely low switching losses
- low Irm values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

### Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters





Backside: isolated

#### Package:

**FL** E72873

- Housing: TO-220FP
- Industry standard outline
- Plastic overmolded tab for electrical isolation
- Epoxy meets UL 94V-0
- RoHS compliant

#### Ratings

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Definition	Conditions		min.	typ.	max.	Unit
max. repetitive reverse voltage		$T_{VJ} = 25^{\circ}C$			100	V
reverse current	V <sub>R</sub> = 100 V	$T_{VJ} = 25^{\circ}C$			0.2	μΑ
	V <sub>R</sub> = 100 V	$T_{VJ} = 125^{\circ}C$			2	mΑ
forward voltage	I <sub>F</sub> = 10 A	$T_{VJ} = 25^{\circ}C$			0.90	V
	$I_F = 20 A$				1.50	V
	I <sub>F</sub> = 10 A	T <sub>VJ</sub> = 125°C			0.72	V
	$I_F = 20A$				0.88	V
average forward current	rectangular, d = 0.5	$T_{c} = 145^{\circ}C$			10	Α
threshold voltage slope resistance for power loss calculation only		$T_{VJ} = 175^{\circ}C$			0.46	V
					17	mΩ
thermal resistance junction to case					4.50	K/W
virtual junction temperature			-55		175	°C
total power dissipation		$T_{\rm C} = 25^{\circ}{\rm C}$			35	W
max. forward surge current	t = 10 ms (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			220	Α
junction capacitance	$V_R = tbdV$ ; $f = 1 MHz$	$T_{VJ} = 25^{\circ}C$		tbd		pF
	max. repetitive reverse voltage reverse current  forward voltage  average forward current threshold voltage slope resistance for power loss can be thermal resistance junction to case virtual junction temperature total power dissipation max. forward surge current	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$

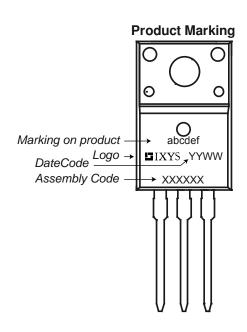




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				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
I <sub>RMS</sub>	RMS current	per pin 1)			35	Α	
R <sub>thCH</sub>	thermal resistance case to heat	sink		0.50		K/W	
T <sub>stg</sub>	storage temperature		-55		150	°C	
Weight				2		g	
M <sub>D</sub>	mounting torque		0.4		0.8	Nm	
F <sub>c</sub>	mounting force with clip		20		60	N	

<sup>1)</sup> I<sub>RMS</sub> is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip. In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.



#### Part number

D = Diode

S = Schottky Diode

A = low VF

20 = Current Rating [A]

C = Common Cathode 100 = Reverse Voltage [V]

PN = TO-220ACFP(3)

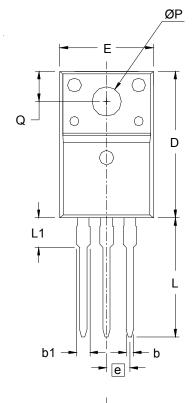
Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Code Key
Standard	DSA 20 C 100 PN	DSA20C100PN	Tube	50	503516

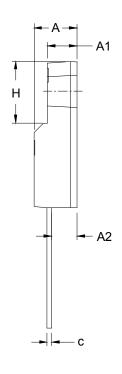
Similar Part	Package	Voltage class
DSA20C100PB	TO-220	100
DSA20C60PN	TO-220FP	60
DSSK20-0045AM	TO-220	45
DSSK20-015A	TO-220	150



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SYM	INCHES		MILLIMETERS		
2114	MIN	MAX	MIN	MAX	
А	.177	.193	4.50	4.90	
A1	.092	.108	2.34	2.74	
A2	.101	.117	2.56	2.96	
b	.028	.035	0.70	0.90	
b1	.050	.058	1.27	1.47	
С	.018	.024	0.45	0.60	
D	.617	.633	15.67	16.07	
E	.392	.408	9.96	10.36	
е	.100 BSC		2.54 BSC		
Н	.255	.271	6.48	6.88	
L	.499	.523	12.68	13.28	
L1	.119	.135	3.03	3.43	
ØP	.121	.129	3.08	3.28	
Q	.126	.134	3.20	3.40	